# 74LCX540 Low Voltage Octal Buffer/Line Driver with 5V Tolerant **Inputs and Outputs**

#### **General Description**

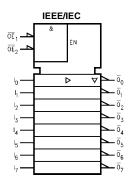
#### **Features**

- 5V tolerant inputs and outputs
- 2.3V-3.6V V<sub>CC</sub> specifications provided
- 6.5 ns t<sub>PD</sub> max (V<sub>CC</sub> = 3.3V), 10 μA I<sub>CC</sub> max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
- Human body model > 2000V
- Machine model > 200V

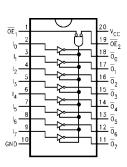
#### **Ordering Code:**

	uctor m 40		March 1995 Revised April 1999
employed as a m and bus oriented This device is sin viding flow-throug from outputs). Th especially useful allowing ease of I The LCX540 is de applications with environment. The CMOS technolog	In octal buffer/line c nemory and addres transmitter/receiver. hilar in function to th gh architecture (inpl is pinout arrangeme as an output port ayout and greater Pf signed for low voltage capability of interfa	ge (2.5V or 3.3V) $V_{CC}$ acing to a 5V signal ed with an advanced peed operation while	<ul> <li>Features</li> <li>5V tolerant inputs and outputs</li> <li>2.3V-3.6V V<sub>CC</sub> specifications provided</li> <li>6.5 ns t<sub>PD</sub> max (V<sub>CC</sub> = 3.3V), 10 μA I<sub>CC</sub> max</li> <li>Power down high impedance inputs and outputs</li> <li>Supports live insertion/withdrawal (Note 1)</li> <li>Implements patented noise/EMI reduction circuitry</li> <li>Latch-up performance exceeds 500 mA</li> <li>ESD performance: Human body model &gt; 2000V Machine model &gt; 200V</li> <li>Note 1: To ensure the high-impedance state during power up or down, OE should be tied to V<sub>CC</sub> through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.</li> </ul>
Ordering C	Code:		
Order Number	Package Number		Package Description
74LCX540WM	M20B		Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX540SJ	M20D		Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX540MSA	MSA20		Outline Package (SSOP), TYPE II, 5.3mm Wide
74LCX540MTC	MTC20		Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Logic Sym		y by appending the suffix lette	Connection Diagram
OE OE	EN EN		$\overline{OE}_{1}, \frac{1}{10} \xrightarrow{20} V_{CC}$ $V_{0}, \frac{2}{10} \xrightarrow{10} 18 \overline{O}_{0}$ $V_{1}, \frac{1}{10} \xrightarrow{10} 17 \overline{O}_{1}$

#### Logic Symbol



#### **Connection Diagram**



DS012403.prf © 1999 Fairchild Semiconductor Corporation

## **Pin Descriptions**

74LCX540

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output Enable Inputs
I <sub>0</sub> —I <sub>7</sub>	Inputs
$\overline{O}_0 - \overline{O}_7$	Outputs

### **Truth Table**

	Inputs		Outputs
OE <sub>1</sub>	OE 2	I	Ōn
L	L	Н	L
Н	Х	Х	Z
Х	Н	Х	Z
L	L	L	Н

H = HIGH Voltage LevelL = LOW Voltage LevelX = ImmaterialZ = High Impedance

### Absolute Maximum Ratings(Note 2)

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Symbol	Parameter	Value	Conditions	Units
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		–0.5 to $V_{CC}^{} + 0.5$	Output in HIGH or LOW State (Note 3)	v
IK	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA
ок	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA
		+50	V <sub>O</sub> > V <sub>CC</sub>	ma
0	DC Output Source/Sink Current	±50		mA
cc	DC Supply Current per Supply Pin	±100		mA
GND	DC Ground Current per Ground Pin	±100		mA
T <sub>STG</sub>	Storage Temperature	-65 to +150		°C

### Recommended Operating Conditions (Note 4)

Symbol	Parameter			Max	Units	
V <sub>CC</sub>	Supply Voltage	Operating	2.0	3.6	V	
		Data Retention	1.5	3.6	v	
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage	HIGH or LOW State	0	V <sub>CC</sub>	v	
		3-STATE	0	5.5	v	
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	$V_{CC} = 3.0V - 3.6V$		±24		
		$V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	mA	
		$V_{CC}=2.3V-2.7V$		±8		
T <sub>A</sub>	Free-Air Operating Temperature		-40	85	°C	
$\Delta t / \Delta V$	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$ , $V_{CC} = 3.0V$		0	10	ns/V	

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I<sub>O</sub> Absolute Maximum Rating must be observed.

Note 4: Unused (inputs or I/O's) must be held HIGH or LOW. They may not float.

### **DC Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>cc</sub>	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
Symbol	Falanetei	Conditions	(V)	Min	Max	Units
V <sub>IH</sub>	HIGH Level Input Voltage		2.3 – 2.7	1.7		v
			2.7 - 3.6	2.0		v
V <sub>IL</sub>	LOW Level Input Voltage		2.3 – 2.7		0.7	v
			2.7 - 3.6		0.8	v
V <sub>ОН</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = -100 μA	2.3 - 3.6	V <sub>CC</sub> - 0.2		-
		I <sub>OH</sub> = -8 mA	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I <sub>OH</sub> = -18 mA	3.0	2.4		
		I <sub>OH</sub> = -24 mA	3.0	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.3 - 3.6		0.2	
		I <sub>OL</sub> = 8 mA	2.3		0.6	
		I <sub>OL</sub> = 12 mA	2.7		0.4	V
		I <sub>OL</sub> = 16 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
կ	Input Leakage Current	$0 \le V_{\parallel} \le 5.5V$	2.3 - 3.6		±5.0	μΑ
I <sub>OZ</sub>	3-STATE Output Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	μA
		$V_I = V_{IH} \text{ or } V_{IL}$				μΑ
IOFF	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 \text{V}$	0		10	μΑ

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### DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	Conditions V <sub>CC</sub>		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Gymbol	i arameter	Conditiona	(V)	Min	Max	Units	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>I</sub> = V <sub>CC</sub> or GND	2.3 - 3.6		10	μA	
		$3.6V \le V_I$ , $V_O \le 5.5V$ (Note 5)	2.3 - 3.6		±10	μΑ	
Δl <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA	

Note 5: Outputs disabled or 3-STATE only.

### **AC Electrical Characteristics**

			$T_A = -40^{\circ}C$ to $+85^{\circ}C$ , $R_L = 500\Omega$					
Symbol	Parameter	$V_{CC}=3.3V\pm0.3V$		$V_{CC} = 2.7V$		$V_{CC}=2.5V\pm0.2V$		Units
	Parameter	C <sub>L</sub> =	C <sub>L</sub> = 50pF		C <sub>L</sub> = 50pF		C <sub>L</sub> = 30 pF	
		Min	Max	Min	Max	Min	Max	
t <sub>PHL</sub>	Propagation Delay	1.5	6.5	1.5	7.5	1.5	7.8	
t <sub>PLH</sub>		1.5	6.5	1.5	7.5	1.5	7.8	ns
t <sub>PZL</sub>	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	200
t <sub>PZH</sub>		1.5	8.5	1.5	9.5	1.5	10.5	ns
t <sub>PLZ</sub>	Output Disable Time	1.5	7.5	1.5	8.5	1.5	9.0	ns
t <sub>PHZ</sub>		1.5	7.5	1.5	8.5	1.5	9.0	115
t <sub>OSHL</sub>	Output to Output Skew (Note 6)		1.0					ns
t <sub>OSLH</sub>			1.0					115

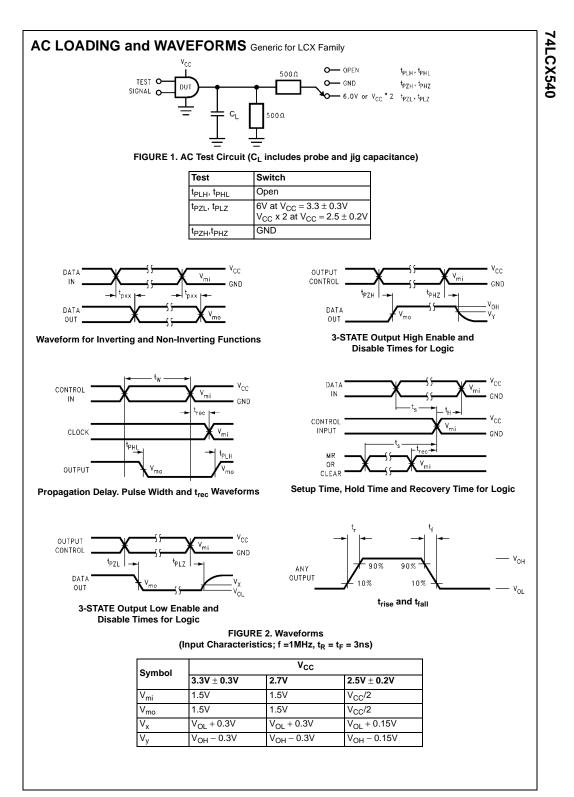
Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>).

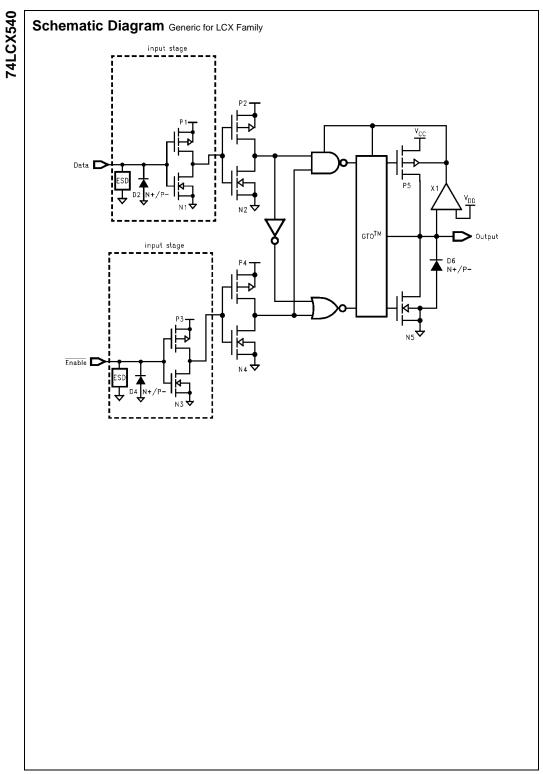
### **Dynamic Switching Characteristics**

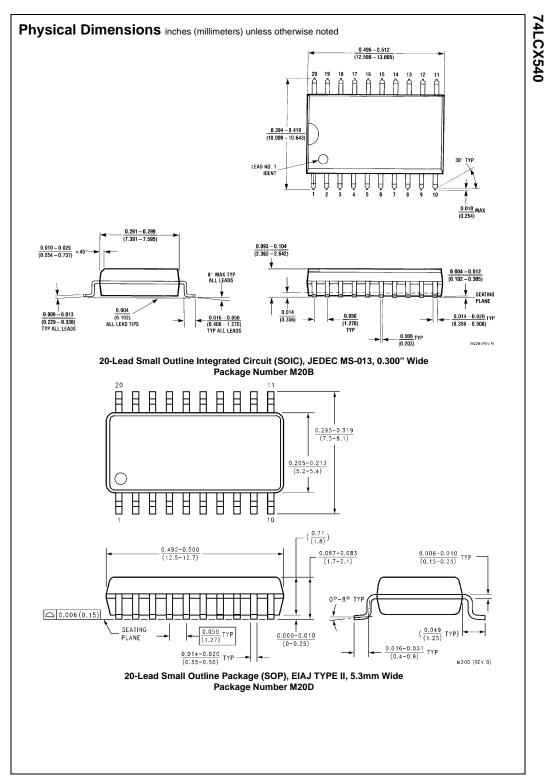
Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = 25^{\circ}C$	Units
Symbol	Farameter	Conditions	(V)	Typical	Units
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	C <sub>L</sub> = 50 pF, V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V	3.3	0.8	V
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	0.6	v
V <sub>OLV</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	$C_{L} = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	-0.6	v

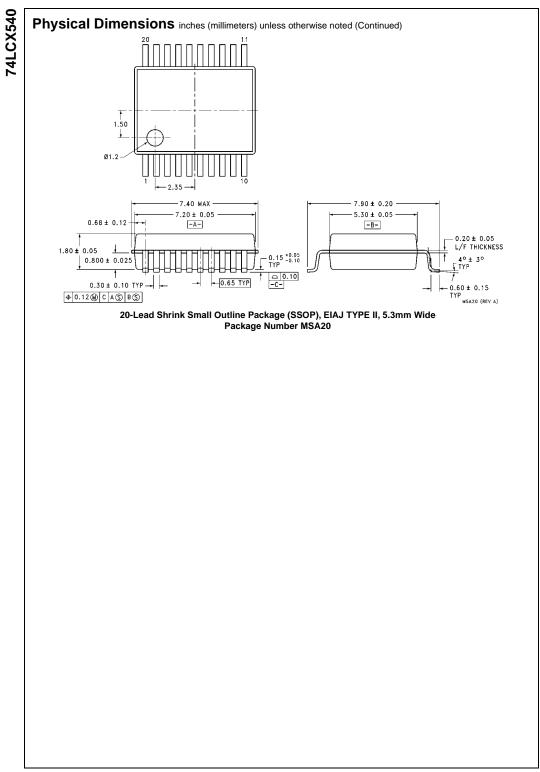
### Capacitance

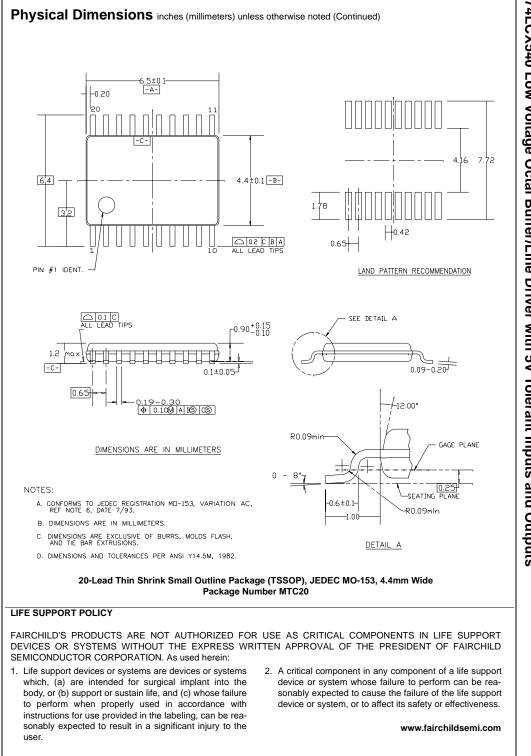
Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC}$ = 3.3V, V $_{I}$ = 0V or $V_{CC},f$ = 10 MHz	25	pF











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